Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.180 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.075 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

65.0 working peak reverse voltage

Current Rating Per Characteristic:

200.00 milliamperes forward current, average absolute and 400.00 milliamperes source cutoff current preset and 600.00 milliamperes source cutoff current outside diameter and 4.00 amperes source cutoff current peak

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

18876-mis-19413 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0